

CMOS Transistor R & C

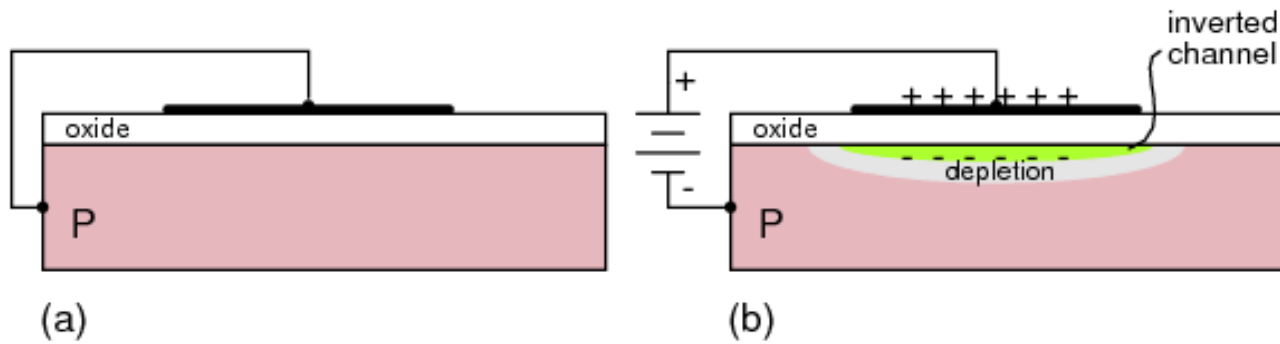
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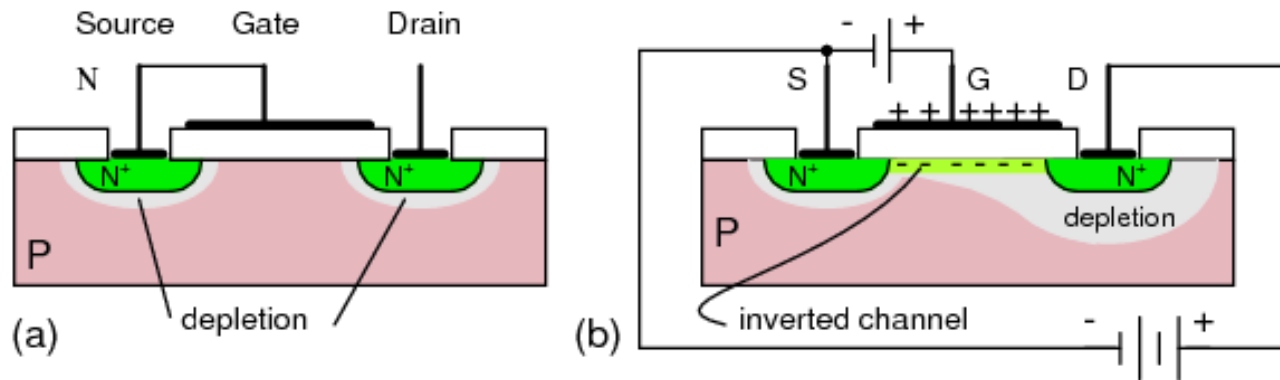
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NMOS Bias

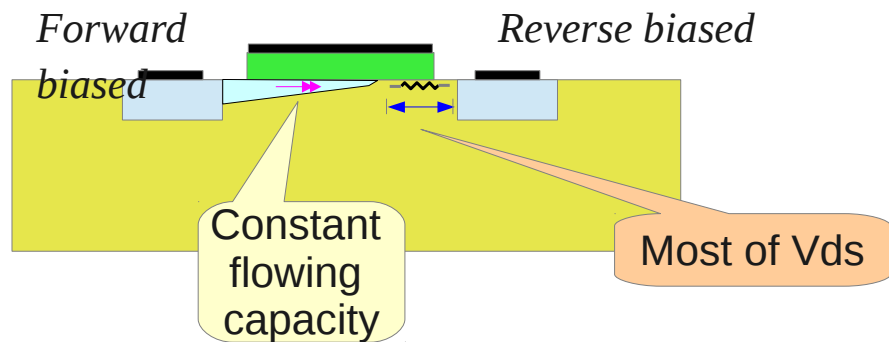
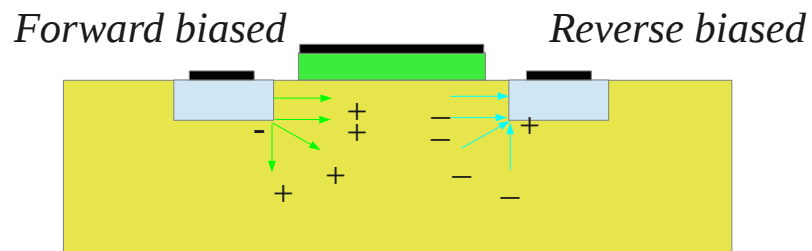
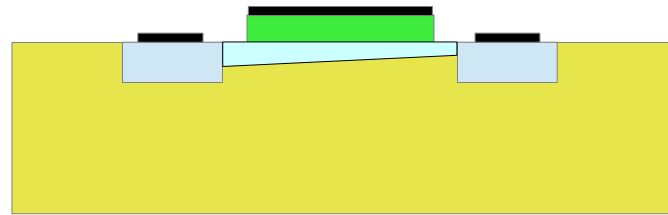
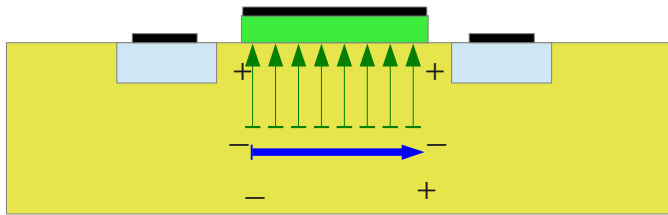


N-channel MOS capacitor: (a) no charge, (b) charged.



N-channel MOSFET (enhancement type): (a) 0 V gate bias, (b) positive gate bias.

Pinch-Off



Simple Transistor Model (1)

Cutoff, subthreshold, or weak-inversion mode

When $V_{GS} < V_t$:

$$I_d = 0$$

Triode mode or linear region (the ohmic mode)

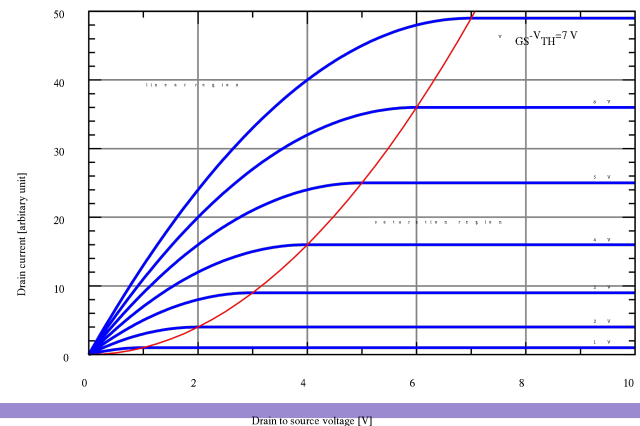
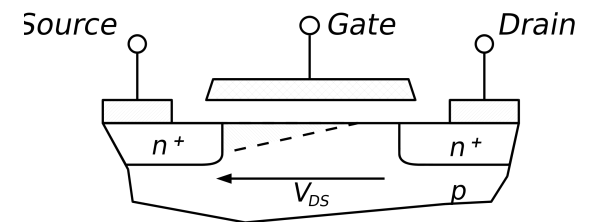
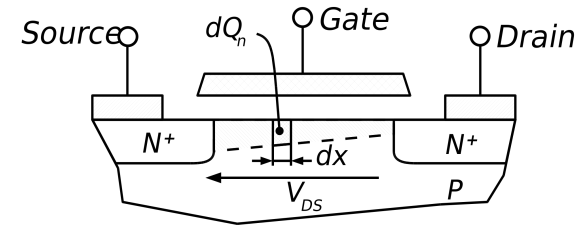
When $V_{GS} > V_t$ and $V_{DS} < (V_{GS} - V_t)$

$$I_d = k' \frac{W}{L} \left[(v_{gs} - v_t) v_{ds} - \frac{1}{2} v_{ds}^2 \right]$$

Saturation or active mode

When $V_{GS} > V_t$ and $V_{DS} \geq (V_{GS} - V_t)$

$$I_d = \frac{1}{2} k' \frac{W}{L} (v_{gs} - v_t)^2$$



Simple Transistor Model (2)

linear region

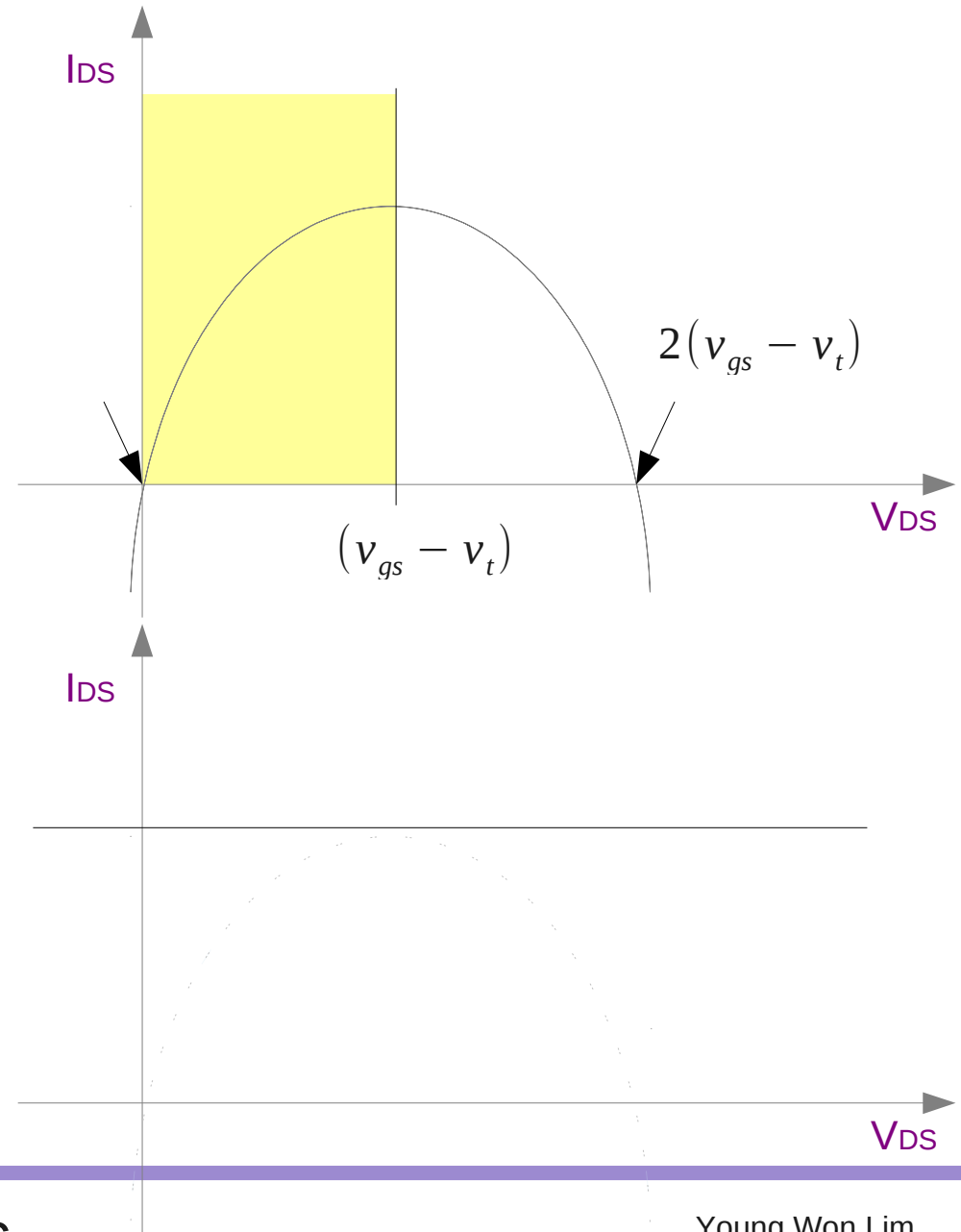
When $V_{GS} > V_t$ and $V_{DS} < (V_{GS} - V_t)$

$$I_d = k' \frac{W}{L} \left[(v_{gs} - v_t) v_{ds} - \frac{1}{2} v_{ds}^2 \right]$$

Saturation or active mode

When $V_{GS} > V_t$ and $V_{DS} \geq (V_{GS} - V_t)$

$$I_d = \frac{1}{2} k' \frac{W}{L} (v_{gs} - v_t)^2$$



Simple Transistor Model (3)

Cutoff

$$V_{GS} < V_t$$

Linear region

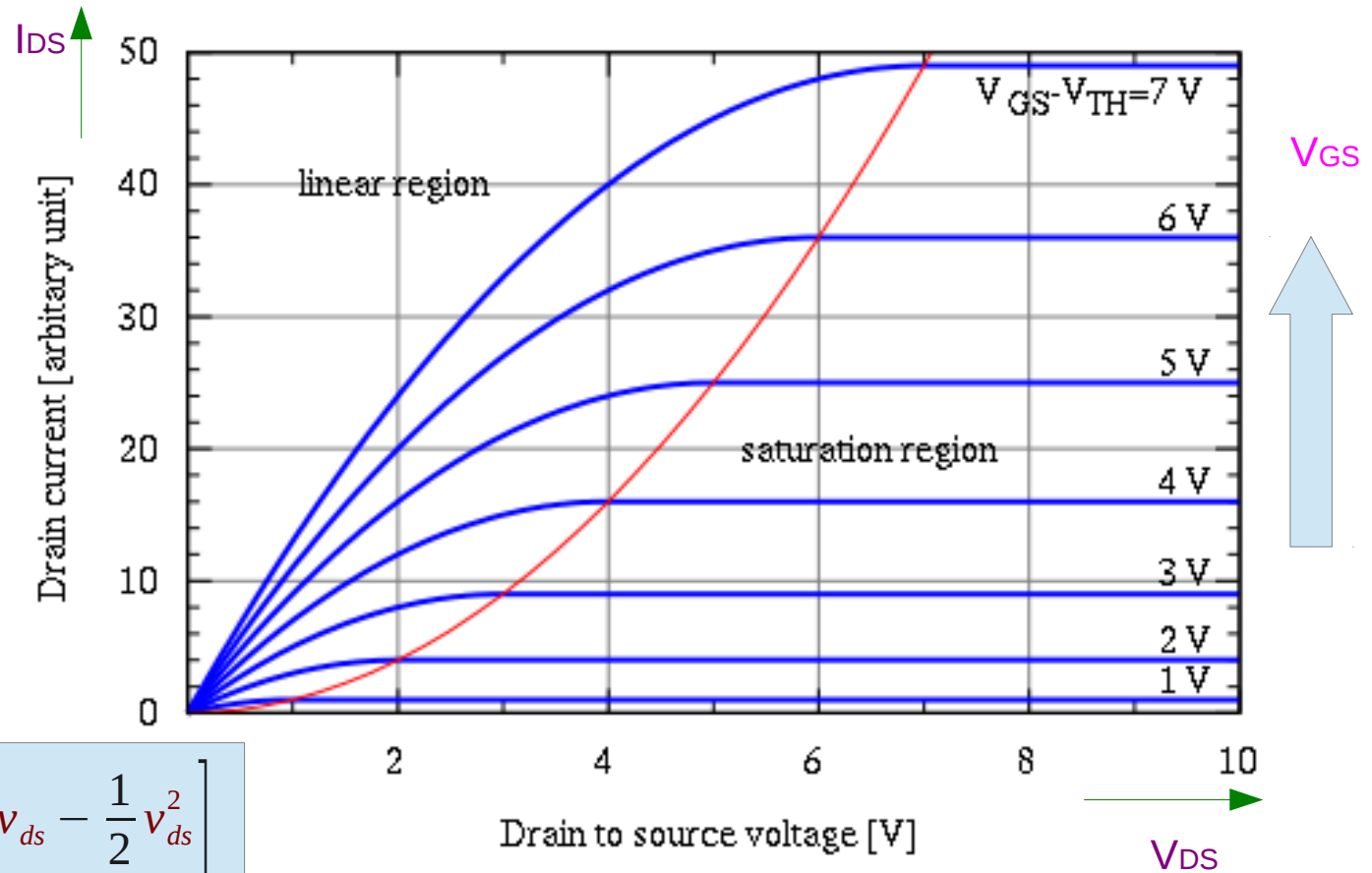
$$V_{GS} > V_t$$

$$V_{DS} < (V_{GS} - V_t)$$

Saturation

$$V_{GS} > V_t$$

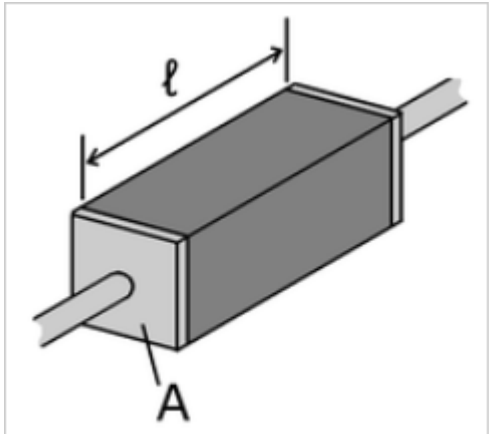
$$V_{DS} > (V_{GS} - V_t)$$



$$I_d = k' \frac{W}{L} \left[(v_{gs} - v_t) v_{ds} - \frac{1}{2} v_{ds}^2 \right]$$

$$I_d = \frac{1}{2} k' \frac{W}{L} (v_{gs} - v_t)^2$$

Resistance (1)



A piece of resistive material with electrical contacts on both ends.

$$R = \frac{V}{I}$$

$$G = \frac{I}{V}$$

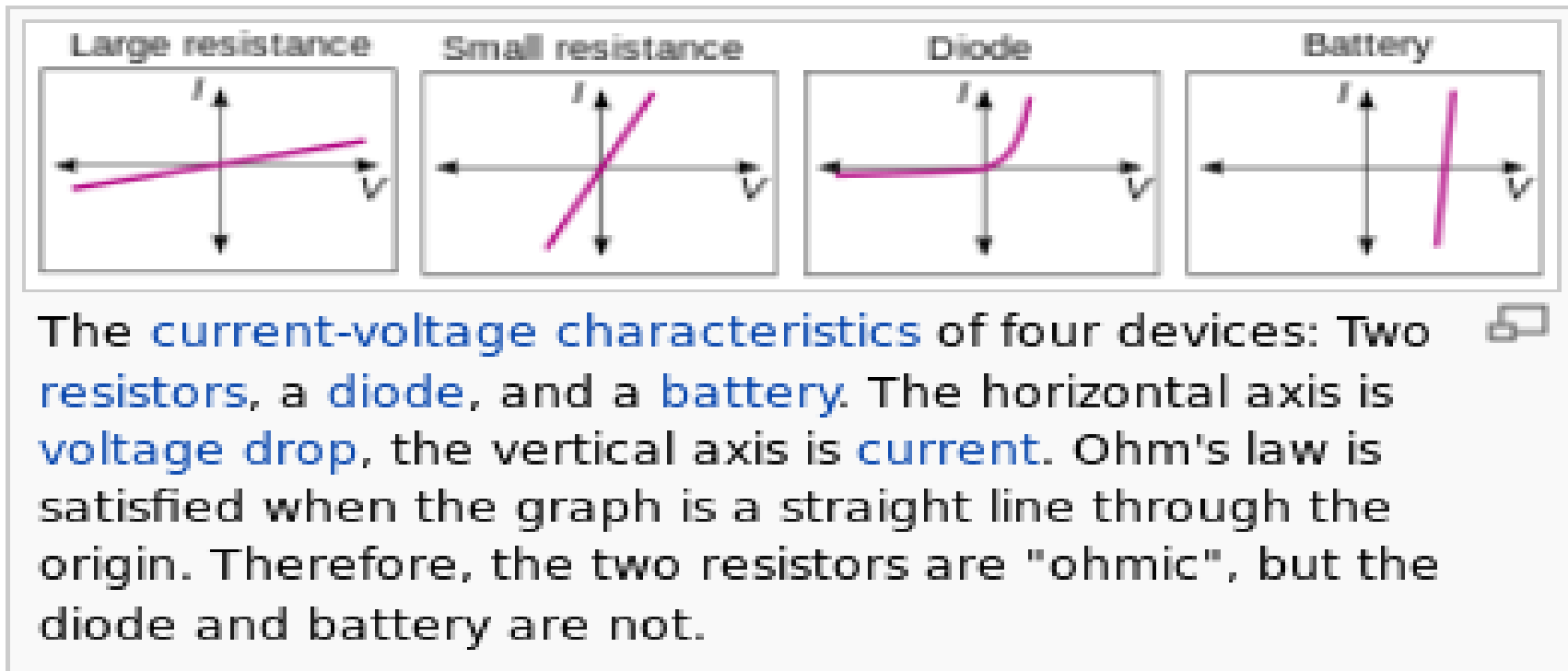
Ohm's law $V \propto I$

$$R = \frac{V}{I}, \quad G = \frac{I}{V}$$

the derivative $\frac{dV}{dI}$ may be most useful; this is called the "differential resistance".

$$I_d = k' \frac{W}{L} \left[(v_{gs} - v_t) v_{ds} - \frac{1}{2} v_{ds}^2 \right]$$

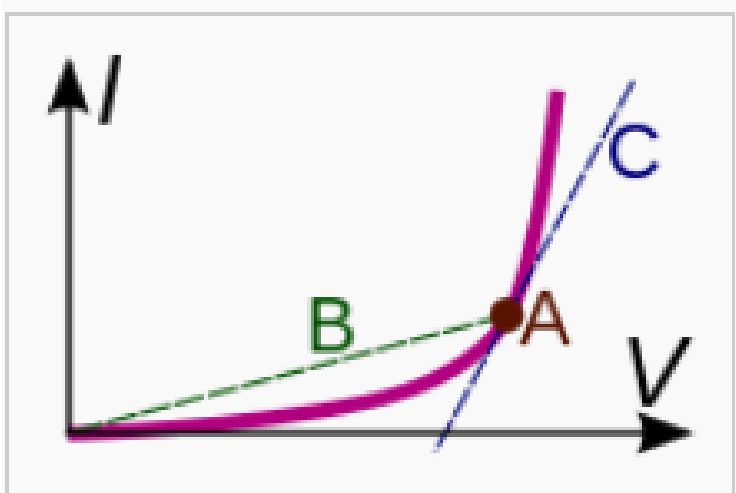
Resistance (2)



Slope

the derivative $\frac{dV}{dI}$ may be most useful; this is called the "differential resistance".

Resistance (3)



The **IV curve** of a non-ohmic device (purple). Point A represents the current and voltage values right now. The **static resistance** is the **inverse slope** of line B through the origin. The **differential resistance** is the inverse slope of **tangent line C**.

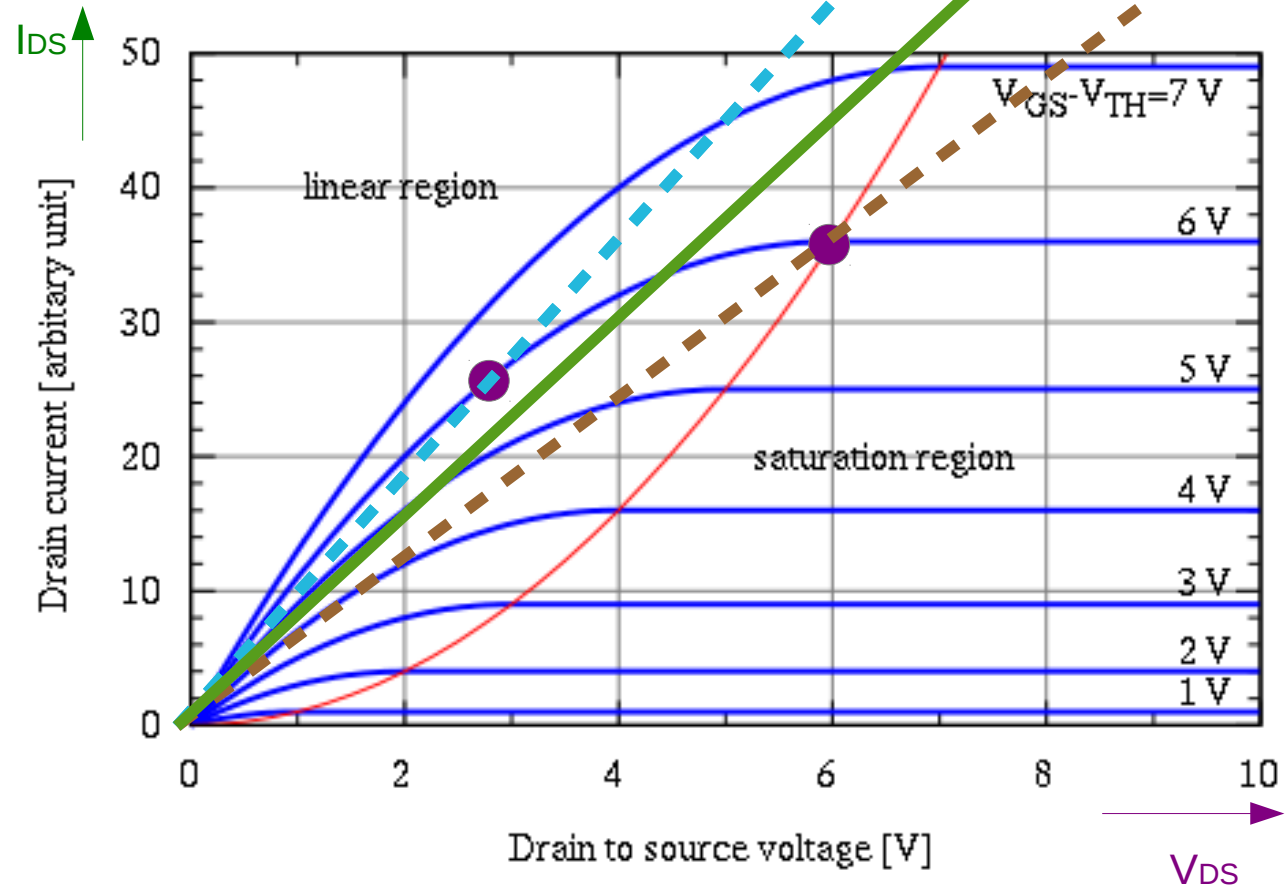
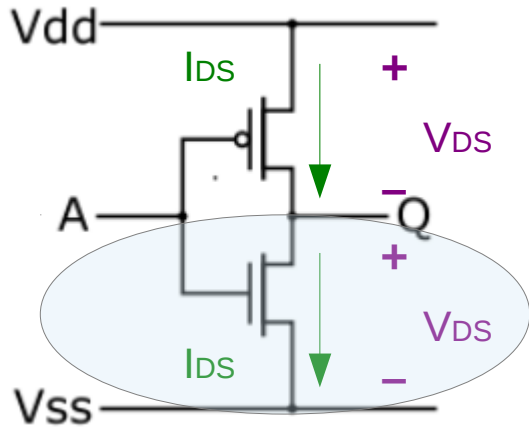
- **Static resistance** (also called *chordal* or *DC resistance*) - This corresponds to the usual definition of resistance; the voltage divided by the current

$$R_{\text{static}} = \frac{v}{i}$$

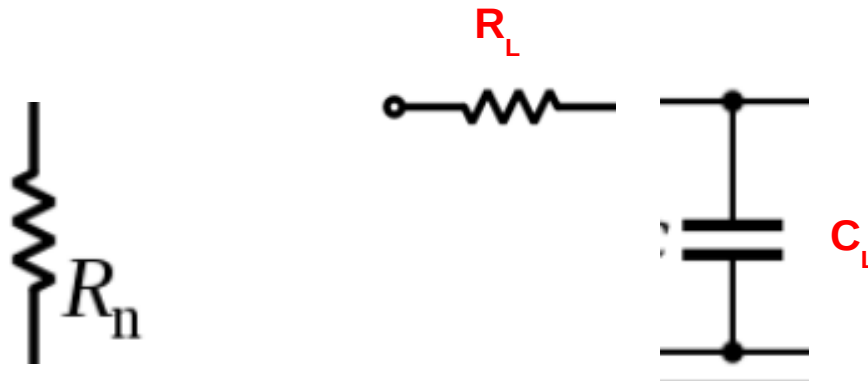
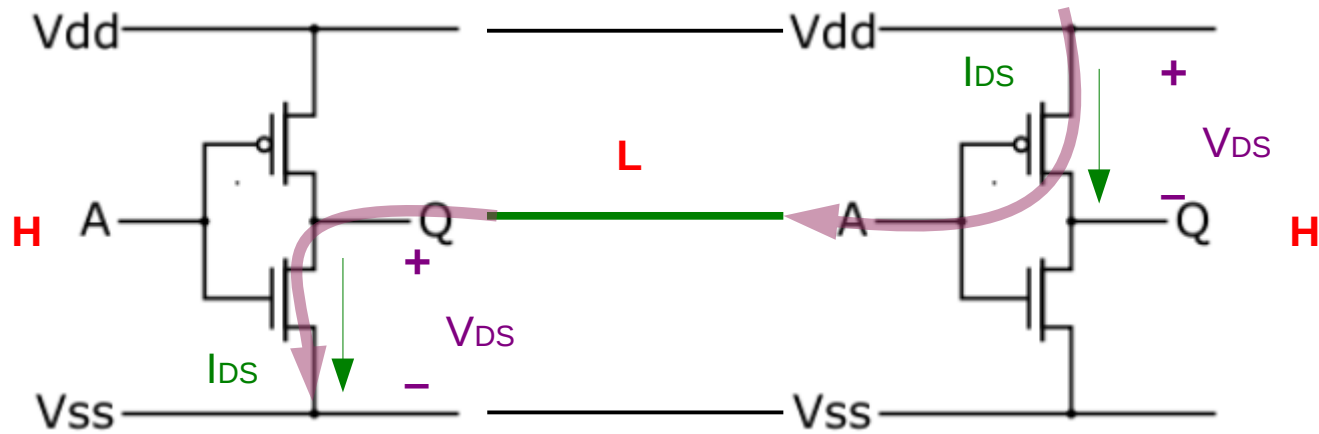
- **Differential resistance** (also called *dynamic*, *incremental* or *small signal resistance*) - **Differential resistance** is the derivative of the voltage with respect to the current; the **slope** of the IV curve at a point

$$R_{\text{diff}} = \frac{dv}{di}$$

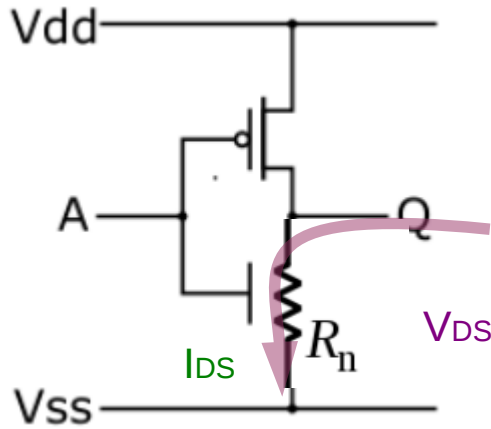
Resistance (4)



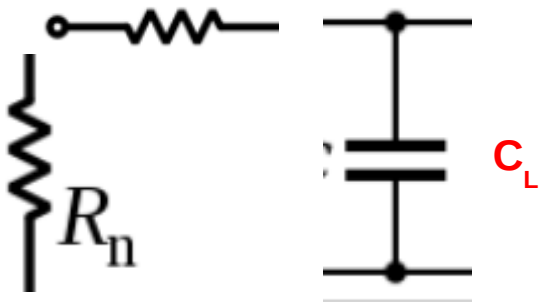
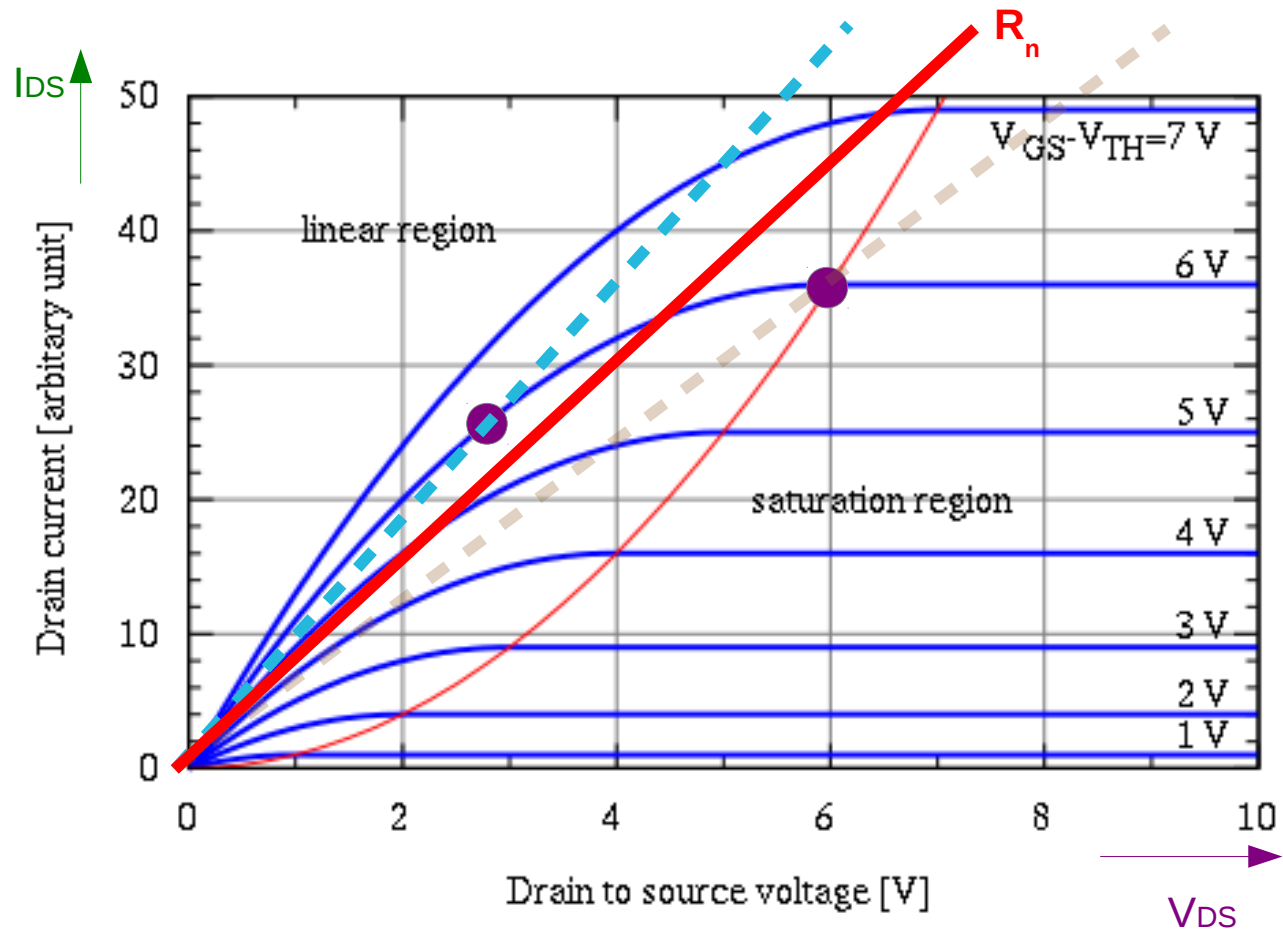
Resistance (5)



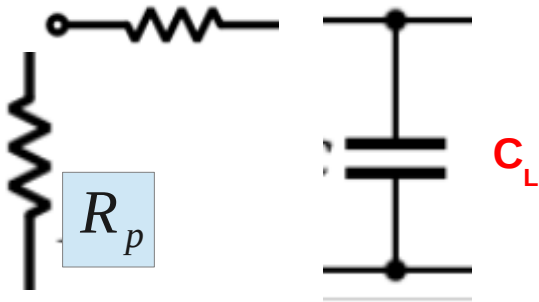
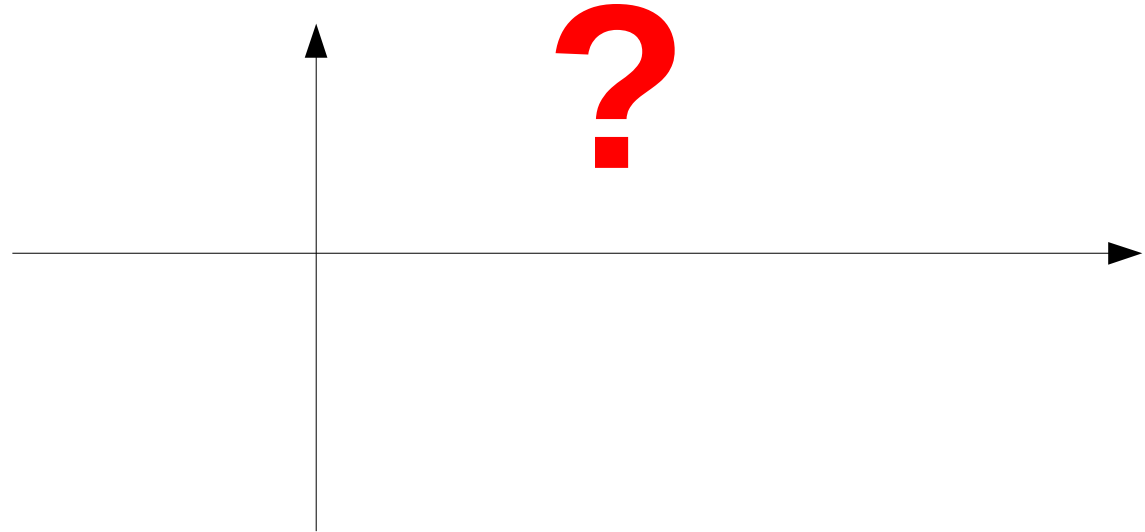
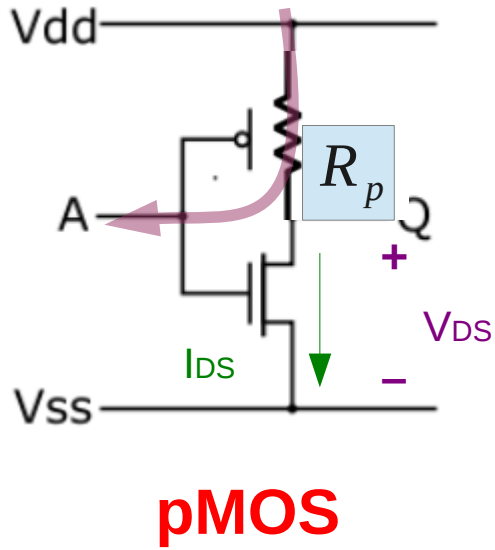
Resistance (6)



nMOS

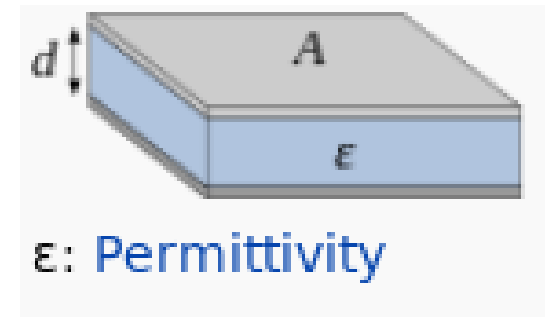


Resistance (7)

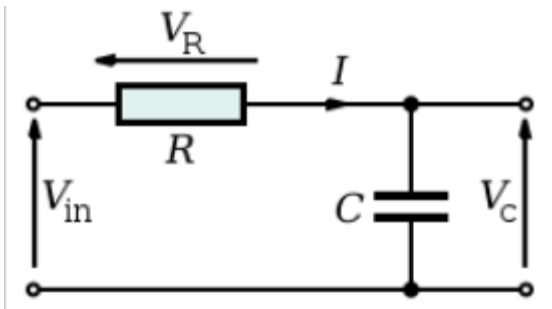


Capacitance

$$\epsilon A/d$$



RC Circuit



Series RC circuit

By viewing the circuit as a **voltage divider**, the **voltage** across the capacitor is:

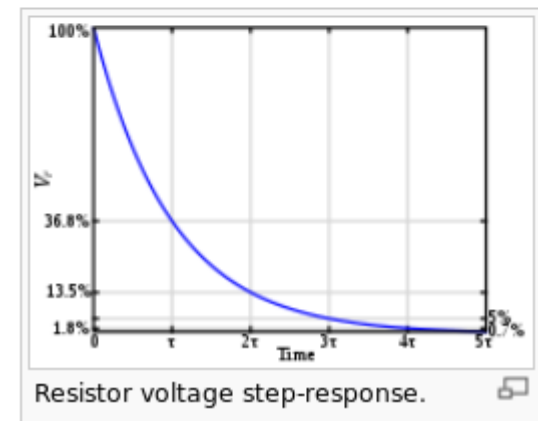
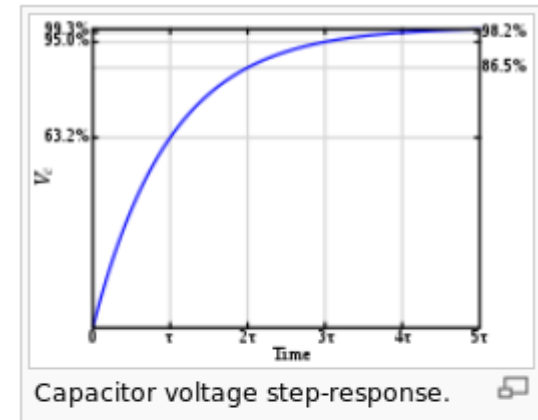
$$V_C(s) = \frac{1/Cs}{R + 1/Cs} V_{in}(s) = \frac{1}{1 + RCs} V_{in}(s)$$

and the voltage across the resistor is:

$$V_R(s) = \frac{R}{R + 1/Cs} V_{in}(s) = \frac{RCs}{1 + RCs} V_{in}(s).$$

$$V_C(t) = V (1 - e^{-t/RC})$$

$$V_R(t) = V e^{-t/RC}.$$



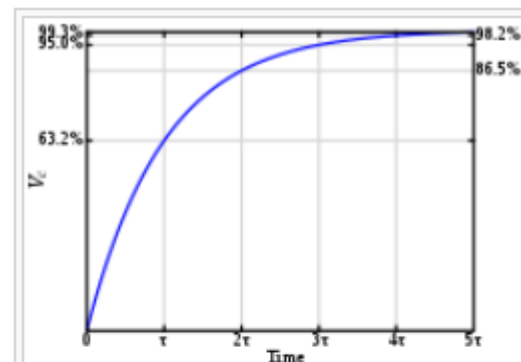
Time Constant

Thus, the voltage across the capacitor tends towards V as time passes, while the voltage across the resistor tends towards 0, as shown in the figures. This is in keeping with the intuitive point that the capacitor will be charging from the supply voltage as time passes, and will eventually be fully charged.

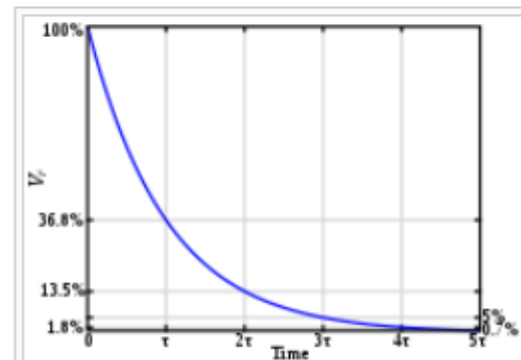
These equations show that a series RC circuit has a **time constant**, usually denoted $\tau = RC$ being the time it takes the voltage across the component to either rise (across C) or fall (across R) to within $1/e$ of its final value. That is, τ is the time it takes V_C to reach $V(1 - 1/e)$ and V_R to reach $V(1/e)$.

The rate of change is a *fractional* $\left(1 - \frac{1}{e}\right)$ per τ . Thus, in going from

$t = N\tau$ to $t = (N + 1)\tau$, the voltage will have moved about 63.2% of the way from its level at $t = N\tau$ toward its final value. So C will be charged to about 63.2% after τ , and essentially fully charged (99.3%) after about 5τ . When the voltage source is replaced with a short-circuit, with C fully charged, the voltage across C drops exponentially with t from V towards 0. C will be discharged to about 36.8% after τ , and essentially fully discharged (0.7%) after about 5τ . Note that the current, I , in the circuit behaves as the voltage across R does, via [Ohm's Law](#).



Capacitor voltage step-response.



Resistor voltage step-response.

Simple Model

V_{gs}

V_{ds}

I_d

$$I_d = k' \frac{W}{L} \left[(v_{gs} - v_t) v_{ds} - \frac{1}{2} v_{ds}^2 \right]$$

$$I_d = \frac{1}{2} k' \frac{W}{L} (v_{gs} - v_t)^2$$

v_t

k'

measured

$\frac{W}{L}$

determined by the layout tool used

Transistor Parasitics

C_g

gate capacitance

C_{gs}

C_{ds}

source/drain overlap capacitance

Wire Parasitics

wires
vias
transistors

Spice Model

wires
vias
transistors

Design Rule

wires
vias
transistors

References

- [1] <http://en.wikipedia.org/>
- [2] <http://www.allaboutcircuits.com/>
- [3] W. Wolf, "Modern VLSI Design : Systems on Silicon"
- [4] N. Weste, D. Harris, "CMOS VLSI Design: A Circuits and Systems Perspective"